### Localization in Two-Dimensional Trivial and Chern Insulators Transfer Matrix Methods

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#### Motivation

- Critical exponents describe system behavior near phase transitions (ex. conductivity)
- Metal-Insulator transitions in the presence of disorder lead to the Quantum Hall Effect in 2D
- The IQHE plateau transition critical exponent is 2.3 – 2.6, but the value is contested
- $\bullet~$  No analytic model  $\rightarrow~$  numerics
- Two approaches to answer this:
  - Vary the models and parameters (ex. next nearest neighbor)
  - Investigate larger systems



Figure: Transverse and Hall resistance in an InAs sample. From Zverev, et al, J. Appl. Phys. **96**, 6353 (2004).

# 2D Square Lattice

- $\bullet~{\rm Sites}~{\rm are}~|\ell,w\rangle$
- Sites are orthogonal
- $|\psi\rangle = \sum_{\ell,w} C_{\ell,w} |\ell,w\rangle$
- $\bullet~\ell$  ranges from 1 to L
- w ranges from 1 to W
- Cylindrical geometry
- Lattice constant is 1
- We consider  $L \gg W$



Figure: The 4th site in the  $\ell$ th cell,  $|\ell,4
angle$ , is highlighted

#### **Tight-Binding Hamiltonians**

General form:

$$H = T + V \implies H = \sum_{\text{sites}} (\text{onsite} + \text{transfer interactions})$$

Anderson Model:

Anderson, Phys. Rev. 109, 1492 (1958)

$$H = \sum_{\ell,w} \underbrace{\epsilon_{\ell,w} c_{\ell,w}^{\dagger} c_{\ell,w}}_{\text{onsite potential}} + \underbrace{t(c_{\ell,w+1}^{\dagger} + c_{\ell,w-1}^{\dagger} + c_{\ell+1,w}^{\dagger} + c_{\ell-1,w}^{\dagger})c_{\ell,w}}_{\text{nearest-neighbor transfer}}$$
Hofstadter Model:  

$$H = \sum_{\ell,w} \underbrace{\epsilon_{\ell,w} c_{\ell,w}^{\dagger} c_{\ell,w}}_{\text{onsite potential}} + \underbrace{t(c_{\ell,w+1}^{\dagger} + c_{\ell,w-1}^{\dagger})c_{\ell,w}}_{\text{NN intra-cell transfer}} + \underbrace{t(e^{-i2\pi\alpha\ell} c_{\ell+1,w}^{\dagger} + e^{+i2\pi\alpha\ell} c_{\ell-1,w}^{\dagger})c_{\ell,w}}_{\text{NN inter-cell transfer}}$$

#### **Transfer Matrices**

- The transfer matrix  $T_\ell$  "transfers" the state in cell  $\ell$  the state in cell  $\ell+1$
- Define the state of cell  $\ell$  to be  $|\ell\rangle = |\ell_1, \ell_2, \dots, \ell_W\rangle$ , where  $|\ell_w\rangle \equiv |\ell, w\rangle$

$$\binom{\ell+1}{\ell} = T_\ell \binom{\ell}{\ell-1}$$

- One way to construct transfer matrices is to use the Time Independent Schrödinger Equation,  $H|\ell\rangle = E|\ell\rangle$ , substituting for H, and rearranging to the desired form
- Two transfer matrices are, for  $\bar{H}_{\ell} = H_{\ell} (\text{inter-cell transfer})$

$$T_{\ell}^{\text{anderson}} = \frac{1}{t} \begin{pmatrix} E\mathbf{1} - \bar{H}_{\ell} & -t\mathbf{1} \\ t\mathbf{1} & 0 \end{pmatrix}; \qquad T_{\ell}^{\text{hofstadter}} = \frac{1}{te^{-i2\pi\alpha\ell}} \begin{pmatrix} E\mathbf{1} - \bar{H}_{\ell} & -te^{+i2\pi\alpha\ell}\mathbf{1} \\ te^{-i2\pi\alpha\ell}\mathbf{1} & 0 \end{pmatrix};$$

# Electronic Localization Length and Conductivity (1 of 3)

 Anderson Localization of electrons in the presence of disorder, assuming the wave function is centered at  $|\ell_0, w\rangle$ , where  $C_{\ell,w} = \langle \ell, w | \ell, w \rangle$ , and  $\xi_w$  is the "localization length"

$$C_{\ell,w} \approx C_{\ell_0,w} \exp(-|\ell - \ell_0|/\xi_w)$$

- In Ergodic Theory, the Lyapunov Exponent  $\gamma$ , describes the divergence in phase space of two trajectories Z with initial separation  $\delta Z(t_0)$  as  $|\delta Z(t)| \approx \exp(\gamma |t - t_0|) |\delta Z(t_0)|$
- If we take  $\gamma \rightarrow -\gamma$  representing convergence of trajectories rather than the divergence, consider the separation from the zero trajectory, and rename  $t \to \ell$ ,  $t_0 \to \ell_0$ , then:

$$C_{\ell,w} \approx C_{\ell_0,w} \exp(-\gamma_w |\ell - \ell_0|)$$



(a) Extended state (b) Localized state in envelope,  $\xi = 1/\gamma$ . Lee and Ramakrishnan, Rev. Mod. Phys **57**, 287 (1985).

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## Electronic Localization Length and Conductivity (2 of 3)

- The best approximation to  $\gamma_w$  occurs at large  $|\ell \ell_0|$ , so we consider  $\ell = L$  and  $\ell_0 = 1$
- Now, Oseledets Theorem<sup>1</sup> states that there exists an asymptotic matrix  $\Gamma$  whose eigenvalues are  $\{e^{\pm\gamma_1}, e^{\pm\gamma_2}, \ldots, e^{\pm\gamma_W}\}$ , where in our case  $\Gamma$  is defined by:

$$\Gamma = \lim_{L \to \infty} \left( \prod_{\ell=L}^1 T_\ell^\dagger \prod_{\ell=1}^L T_\ell \right)^{1/2L}$$

• By QR decomposition into orthogonal matrix Q and upper triangular matrix R, we have:

$$\prod_{\ell=1}^{L} T_{\ell} = Q_{L} \prod_{\ell=1}^{L} R_{\ell} \implies \Gamma = \lim_{L \to \infty} \left( \prod_{\ell=1}^{L} R_{\ell} \right)^{1/L}$$

• The eigenvalues of R are on the diagonal, so by algebra we have:

$$\gamma_w = \frac{1}{L} \sum_{\ell=0}^{L} \ln |R_\ell^{w,w}|$$

<sup>1</sup>V. Oseledets, Trans. Moscow Math. Soc. **19**, 179 (1968)

## Electronic Localization Length and Conductivity (3 of 3)

- The most conducting state will dominate the conductivity, so we name a single localization length for a strip of width W as ξ<sub>W</sub> = max(ξ<sub>w</sub>).
- The localization length of the infinite system is found by collapsing  $\xi_W$  to a function f(x) that fulfills the finite size scaling (FSS) hypothesis,  $f(x) = 1/x, x \gg 1$  and  $f(x) = \text{const}, x \ll 1$ :

$$\frac{\xi_W}{W} = f\left(\frac{W}{\xi_\infty}\right)$$

• This localization length diverges around  ${\it E}_{\it c}$  as:

$$\xi_{\infty}(E) \propto |E - E_c|^{-\nu}$$



## Localization Length in the Anderson Model

- Localization length is attenuated at high disorder
- Symmetric about particle energy E=0
- For disorder strength 1, FSS analysis yields  $\nu = 1.00$ , however we believe this is not a true divergence and that larger system lengths are needed to yield quantitatively accurate results



# Localization Length in the Hofstadter Model

- Localization length is attenuated at high disorder
- Localization length is suppressed at energies away from three energies where localization length diverges for each disorder strength
- Symmetric about particle energy E=0
- For disorder strength 1,  $\nu=2.47$



# Localization Length in the Next-Nearest Neighbor Anderson Model

- Localization length is attenuated at high disorder
- Asymmetric in particle energy
- Large system lengths are needed to yield quantitatively accurate results

Localization Length in NNN Anderson Model  $t_2 = t_1/4$  $\log_{10}(\xi_4)$  for  $L = 10^4$  with uniform onsite disorder 10.0 7.5 2.0 5.0 article Energy (t1) 1.5 2.5 0.0 - 1.0 -2.5 -5.00.5 -7.5-10.00.0 ż . 8 10 Disorder Strength  $(t_1)$ 

# Localization Length in the Next-Nearest Neighbor Hofstadter Model

- Localization length is attenuated at high disorder
- Localization length is suppressed at energies away from two energies where localization length diverges for each disorder strength
- Asymmetric in particle energy

Localization Length in NNN Hofstadter Model,  $t_2 = t_1/4$ ,  $\alpha = 1/3$  $\log_{10}(\xi_4)$  for  $L = 10^4$  with uniform onsite disorder 10.0 7.5 -2.0 5.0 article Energy (t<sub>1</sub>) 1.5 2.5 0.0 - 1.0 -2.5 -5.00.5 -7.5-10.00.0 ż . 8 10 Disorder Strength  $(t_1)$ 

#### Results

- Qualitative behavior varies significantly depending on the next-nearest neighbor hopping
- Quantitatively, we find  $\nu = 2.47 \pm 0.09$  for uniform disorder with strength of the hopping, but this value is non-universal and depends on the disorder strength and the Landau level

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